NSN 5961-01-461-8179

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-461-8179 **Inclosure Material:** Plastic **Overall Length:** Between 3.5 millimeters and 3.8 millimeters **Overall Height:** Between 0.9 millimeters and 1.3 millimeters Overall Width: Between 1.4 millimeters and 1.8 millimeters **End Application:** As4122amapl e/i fscm 04713 Joint Electronic Device Engineering Council/jedec/case Outline Designation: Sod-123 **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 4.7 regulator voltage **Voltage Tolerance In Percent:** -5.0/+5.0 **Current Rating Per Characteristic:** 20.00 milliamperes all primaries horsepower metric **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0